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تهران پاساژ امجد طبقه 1 واحد 16



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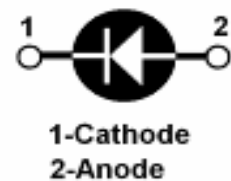
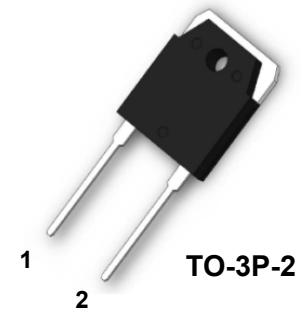


## PRODUCT FEATURES

- Ultrafast Recovery Time
- Low Recovery Loss
- Soft Reverse Recovery Characteristics
- Low Leakage Current
- Low Forward Voltage
- High Surge Current Capability

## APPLICATIONS

- Freewheeling, Snubber, Clamp
- Inversion Welder
- PFC
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- UPS



## DESCRIPTION

FRED from MacMic utilizes advanced processing techniques to achieve ultrafast recovery times and higher forward current. Its soft recovery characteristics and high reliability suit for wide industrial applications.

## ABSOLUTE MAXIMUM RATINGS

$T_C = 25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter/Test Conditions		Values	Unit
$V_R$	Maximum D.C. Reverse Voltage		600	V
$V_{RRM}$	Maximum Repetitive Reverse Voltage			
$I_{F(AV)}$	Average Forward Current	$T_C = 100^\circ\text{C}$	60	A
$I_{F(RMS)}$	RMS Forward Current	$T_C = 100^\circ\text{C}$	84	
$I_{FSM}$	Non Repetitive Surge Forward Current	$T_J = 25^\circ\text{C}, t = 10\text{ms}, 50\text{Hz}, \text{Sine}$	600	
$P_D$	Power Dissipation		250	W
$T_J$	Junction Temperature		-55 to +150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature Range		-55 to +125	$^\circ\text{C}$
<b>Torque</b>	To Heat Sink	Recommended (M3)	1.1	Nm
$R_{thJC}$	Junction to Case Thermal Resistance		0.5	$^\circ\text{C}/\text{W}$
<b>Weight</b>			6	g

## ELECTRICAL CHARACTERISTICS

$T_C = 25^\circ\text{C}$  unless otherwise specified

Symbol	Parameter/Test Conditions		Min.	Typ.	Max.	Unit
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 600\text{V}$			10	$\mu\text{A}$
		$V_R = 600\text{V}, T_J = 125^\circ\text{C}$			1	mA
$V_F$	Forward Voltage	$I_F = 60\text{A}$		1.3	1.5	V
		$I_F = 60\text{A}, T_J = 125^\circ\text{C}$		1.2		
$t_{rr}$	Reverse Recovery Time ( $I_F = 1\text{A}, di_F/dt = -200\text{A}/\mu\text{s}, V_R = 30\text{V}$ )			27	32	ns
$t_{rr}$	Reverse Recovery Time ( $I_F = 0.5\text{A}, I_R = 1\text{A}, I_{RR} = 0.25\text{A}$ )			55	65	ns
$t_{rr}$	Reverse Recovery Time	$I_F = 60\text{A}, V_R = 300\text{V}, di_F/dt = -200\text{A}/\mu\text{s}$		140		ns
$I_{RRM}$	Maximum Reverse Recovery Current			5		A
$t_{rr}$	Reverse Recovery Time	$I_F = 60\text{A}, V_R = 300\text{V}, di_F/dt = -200\text{A}/\mu\text{s}, T_J = 125^\circ\text{C}$		230		ns
$I_{RRM}$	Maximum Reverse Recovery Current			12		A

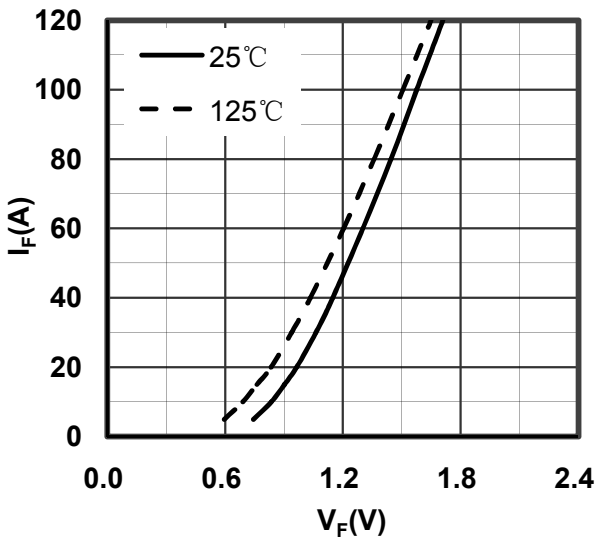


Figure 1. Forward Voltage Drop vs Forward Current

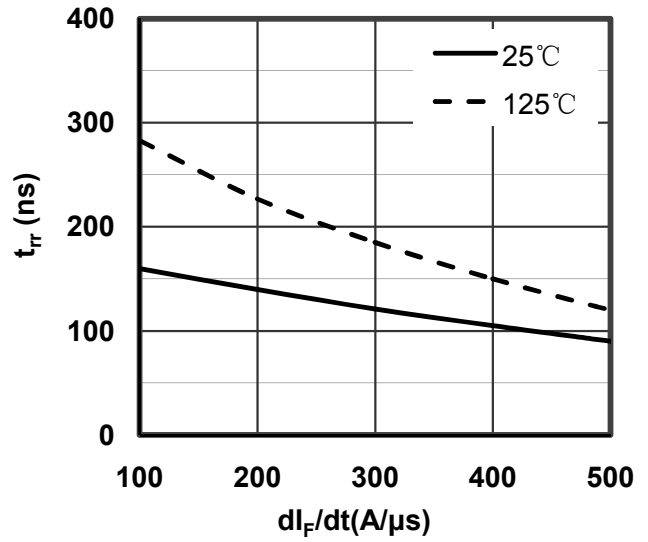


Figure 2. Reverse Recovery Time vs  $di_F/dt$

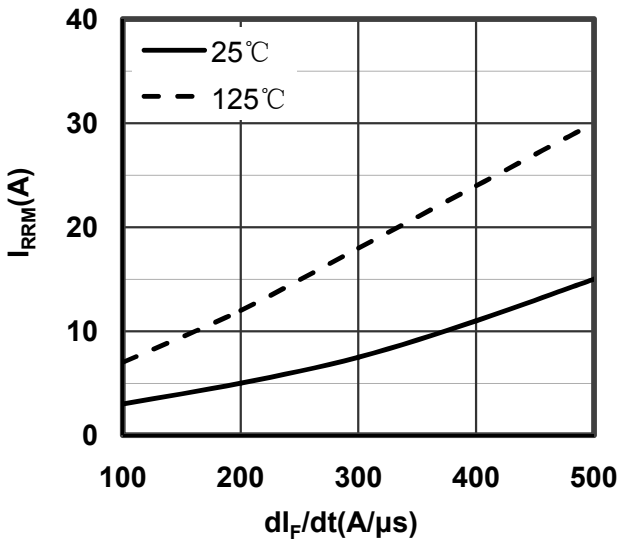


Figure 3. Reverse Recovery Current vs  $di_F/dt$

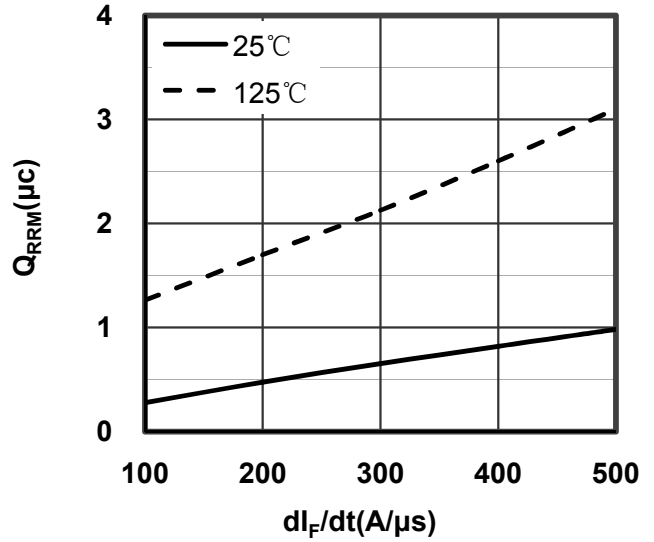


Figure 4. Reverse Recovery Charge vs  $di_F/dt$

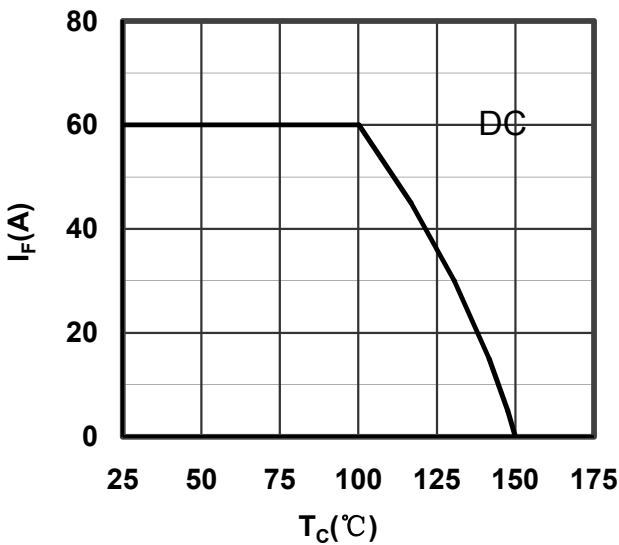


Figure 5. Forward current vs Case temperature

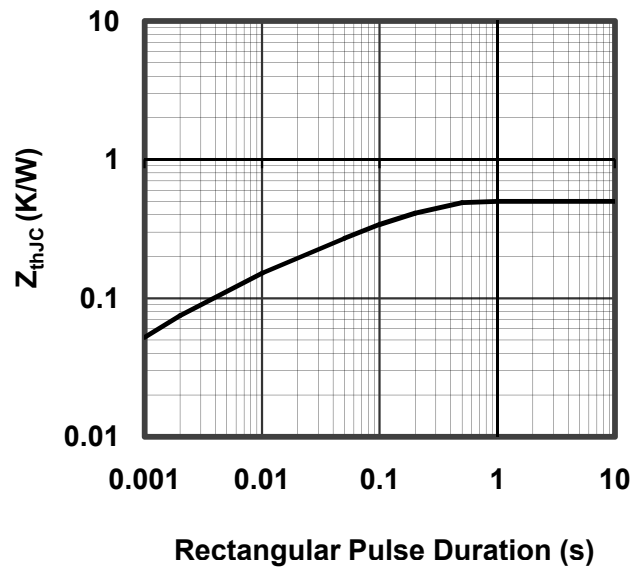


Figure 6. Transient Thermal Impedance

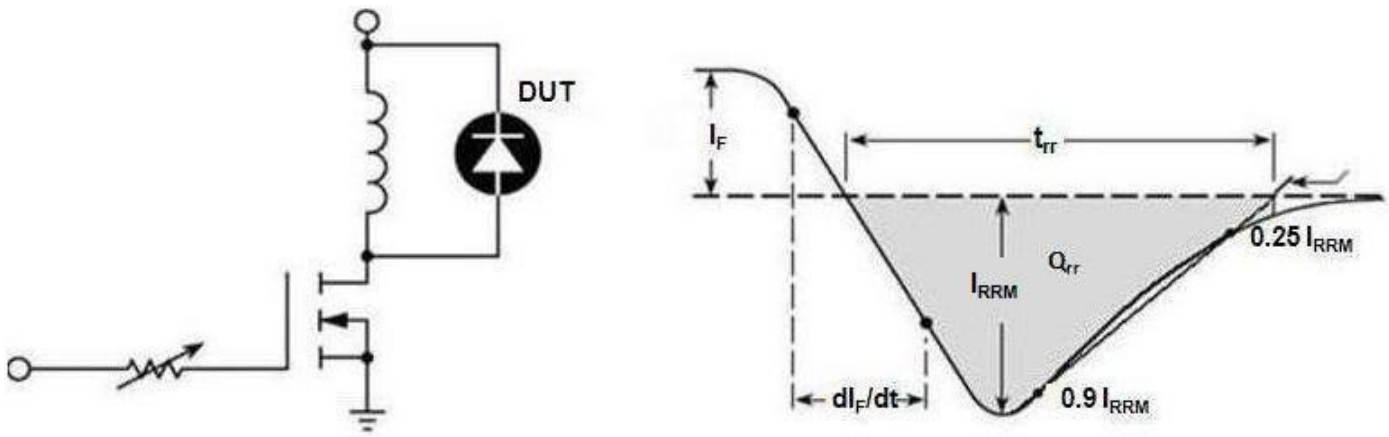
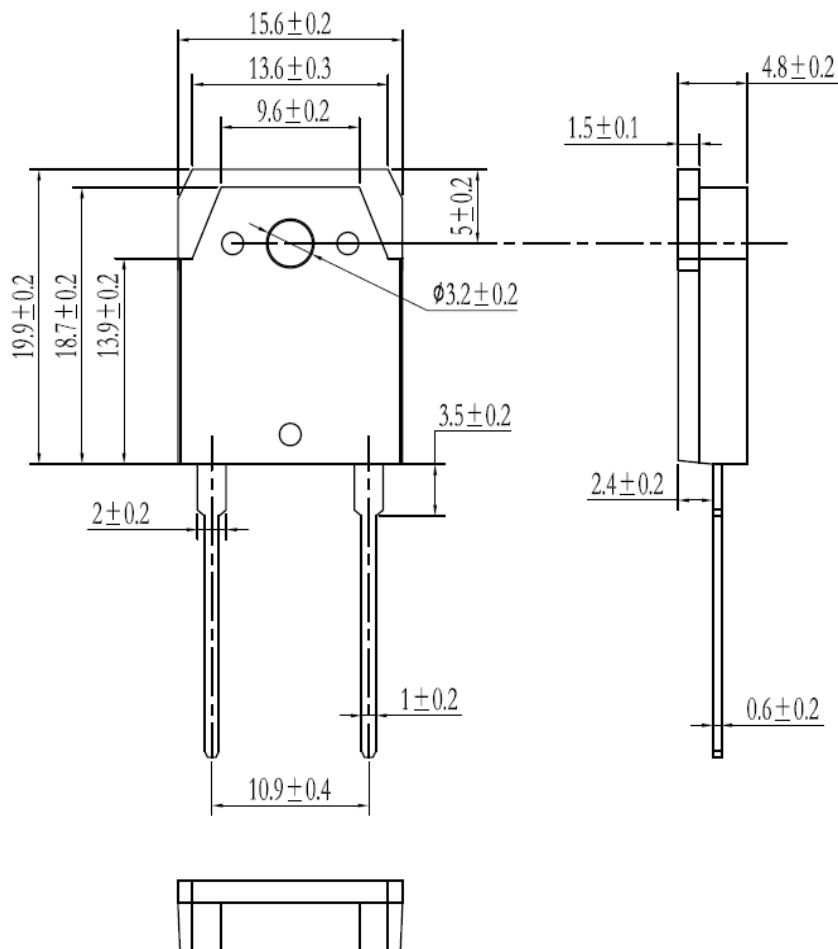


Figure 7. Diode Reverse Recovery Test Circuit and Waveform



Dimensions in (mm)  
Figure 8. Package Outline